

TSM4414 30V N-Channel MOSFET

SOP-8	Pin Definition:	PRODUCT SU	MMARY		
1. Source 2. Source 3. Source		V _{DS} (V)	R _{DS(on)} (mΩ)	I _D (A)	
		26 @ V _{GS} = 10V	8.5		
8 1	4. Gate 5, 6, 7, 8. Drain	30	40 @ V _{GS} = 4.5V	5	

Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

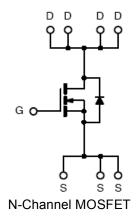
Application

- High-Side DC/DC Conversion
- Notebook
- Sever

Ordering Information

Part No.	Package	Packing
TSM4414CS RL	SOP-8	T&R

Block Diagram



Absolute Maximum Rating (Ta = 25 °C unless otherwise noted)

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	±20	V	
Continuous Drain Current		I _D	8.5	А	
Pulsed Drain Current		I _{DM}	40	А	
Continuous Source Current (Diode Conduction) ^{a,b}		I _S	1.0	А	
Movimum Dower Dissinction	Ta = 25 °C		3.0	W	
Maximum Power Dissipation	Ta = 75 °C	PD	2.1	VV	
Operating Junction Temperature		TJ	+150	°C	
Operating Junction and Storage Temperature Range		T _J , T _{STG}	- 55 to +150	°C	

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	RƏ _{JF}	25	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	Rθ _{JA}	50	°C/W

Notes:

a. Pulse width limited by the Maximum junction temperature

b. Surface Mounted on FR4 Board, t \leq 10 sec.



Ph COMF

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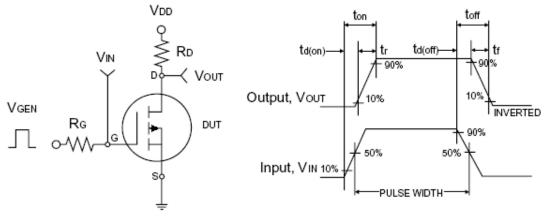
Electrical Specifications

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static			L			
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_{D} = 250uA$	BV_{DSS}	30			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	V _{GS(TH)}	1	1.4	3	V
Gate Body Leakage	V_{GS} = ±20V, V_{DS} = 0V	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	V_{DS} = 24V, V_{GS} = 0V	I _{DSS}			1.0	μA
On-State Drain Current ^a	V _{DS} ≥ 5V, V _{GS} = 10V	I _{D(ON)}	30			А
Drain-Source On-State Resistance ^a	V_{GS} = 10V, I_{D} = 8.5A			20	26	mΩ
Drain-Source On-State Resistance	V_{GS} = 4.5V, I _D = 5A	R _{DS(ON)}		30	40	
Forward Transconductance ^a	$V_{DS} = 5V, I_{D} = 5A$	g _{fs}		20		S
Diode Forward Voltage	I _S = 1A, V _{GS} = 0V	V _{SD}		0.76	1.0	V
Dynamic ^ь						
Total Gate Charge		Qg		4.52		
Gate-Source Charge	$V_{DS} = 15V, I_D = 8.5A,$	Q_gs		1.24		nC
Gate-Drain Charge	V _{GS} = 10V	Q_{gd}		1.68		
Input Capacitance		C _{iss}		400.96		
Output Capacitance	$V_{DS} = 15V, V_{GS} = 0V,$	C _{oss}		100.47		pF
Reverse Transfer Capacitance	f = 1.0MHz	C _{rss}		71.82		
Switching ^c	·					
Turn-On Delay Time		t _{d(on)}		7.42		
Turn-On Rise Time	$V_{DD} = 15V, R_L = 2.2\Omega,$	tr		3.41		
Turn-Off Delay Time	$I_{\rm D} = 1$ A, $V_{\rm GEN} = 10$ V,	t _{d(off)}		20.4		nS
Turn-Off Fall Time	$R_G = 6\Omega$	t _f		3.01]

Notes:

a. pulse test: PW \leq 300µS, duty cycle \leq 2% b. For DESIGN AID ONLY, not subject to production testing.

b. Switching time is essentially independent of operating temperature.



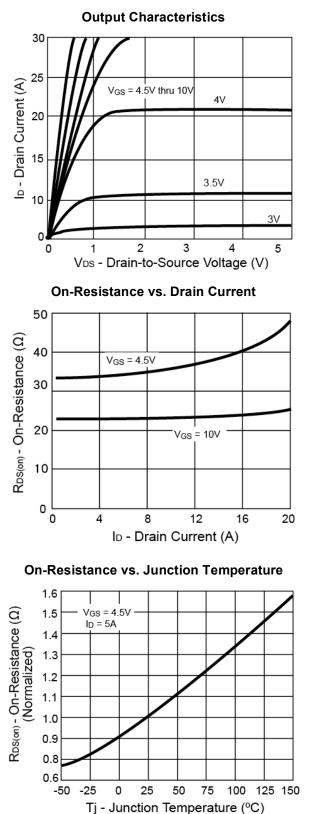
Switching Test Circuit

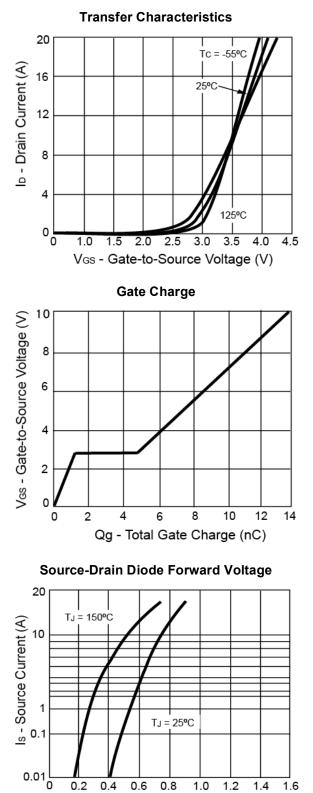
Switchin Waveforms



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Electrical Characteristics Curve (Ta = 25 °C, unless otherwise noted)





1.2

1.0

0.8

0.6

0.2

0.4

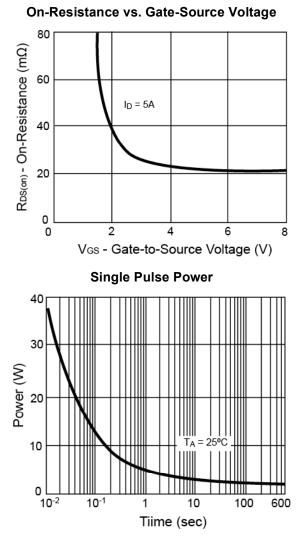
1.4

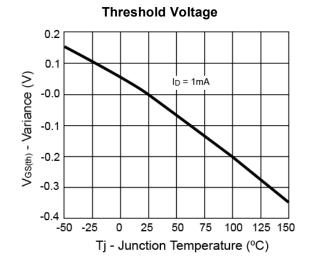
1.6



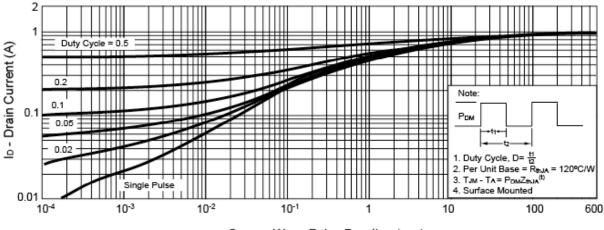
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Normalized Thermal Transient Impedance, Junction-to-Ambient

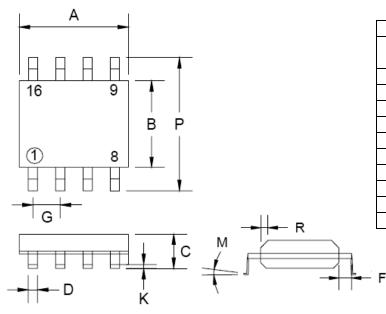


Square Wave Pulse Duration (sec)





SOP-8 Mechanical Drawing



SOP-8 DIMENSION						
DIM	MILLIMETERS		INCHES			
	MIN	MAX	MIN	MAX.		
A	4.80	5.00	0.189	0.196		
В	3.80	4.00	0.150	0.157		
С	1.35	1.75	0.054	0.068		
D	0.35	0.49	0.014	0.019		
F	0.40	1.25	0.016	0.049		
G	1.27BSC		0.05	BSC		
K	0.10	0.25	0.004	0.009		
М	0°	7°	0°	7°		
Р	5.80	6.20	0.229	0.244		
R	0.25	0.50	0.010	0.019		





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